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Substitute for form 1449A/PTO  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  <i>(use as many sheets as necessary)</i>		Application Number	Filed Herewith <u>10/676,695</u>
		Filing Date	9/30/2003
		First Named Inventor:	Fu-Chieh Hsu
		Examiner name: A. Wilson (Parent case)	GROUP: 2815 (Parent case)
Sheet <u>1</u> of <u>1</u>	Attorney Docket Number		MST-013-1D

**U.S. PATENT DOCUMENTS**

Examiner Initials*	Cited No. <sup>1</sup>	U.S. Patent Document Number      Kind Code <sup>2</sup> (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines Where Relevant Info. Appear
<i>ae</i>	A1	5937296	Arnold	08-10-1999	<u>                    </u>
<i>f</i>	A2	6281557	B1 Trueby et al.	08-28-2001	<u>                    </u>
<i>f</i>	A3	5739567	Wong	04-14-1998	<u>                    </u>
<i>f</i>	A4	5216269	Middelhoek et al.	06-01-1993	<u>                    </u>
<i>f</i>	A5	5264716	Kenney	11-23-1993	<u>                    </u>
<i>f</i>	A6	5672536	Wu et al.	09-30-1997	<u>                    </u>
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**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Cited No. <sup>1</sup>	Foreign Patent Document Office <sup>3</sup> Number <sup>4</sup> Kind Code <sup>5</sup> (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines Where Relevant Info. Appear	T <sup>6</sup>

**OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)**

<i>ae</i>	Article entitled "A Capacitor-Less 1T-DRAM Cell", IEEE Electron Device Letters, Vol. 23, No. 2, Feb. 2002, by S. Okhonin et al., pages 85-87
<i>ae</i>	Article entitled "Memory Design Using One-Transistor Gain Cell on SOI" ISSCC 2002/Session 9/DRAM And Ferroelectric Memories/9.1; by Takashi Ohsawa et al.; pages 452-454. <u>NO MONTH GIVEN</u>
EXAMINER <i>A. Wilson</i>	DATE CONSIDERED <u>10/21/04</u>

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup>Unique citation designation number. <sup>2</sup>See attached Kinds of U.S. Patent Documents. <sup>3</sup>Enter Office that issued the document by the two-letter code (WIPO Standard ST.3). <sup>4</sup>For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup>Applicant is to place a check mark here if English language Translation is attached.